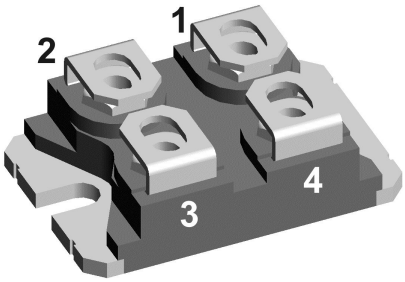
Schottky Diode

V_{RRM}	=	45 V
I_{FAV}	= 2x	80 A
V_F	=	0.63 V

High Performance Schottky Diode
Low Loss and Soft Recovery
Parallel legs

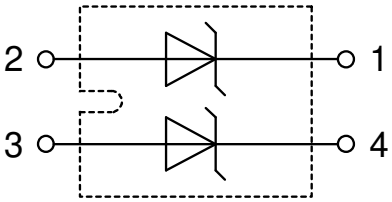
Part number

DSS2x81-0045B



Backside: isolated

E72873



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: SOT-227B (minibloc)

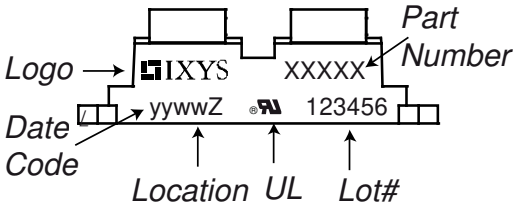
- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Schottky

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
I_R	*reverse current, drain current*	V_R = 45 V	T_{VJ} = 25°C			60	mA
		V_R = 45 V	T_{VJ} = 100°C			250	mA
V_F	*forward voltage drop*	I_F = 80 A	T_{VJ} = 25°C			0.65	V
		I_F = 160 A				0.96	V
		I_F = 80 A	T_{VJ} = 125°C			0.63	V
		I_F = 160 A				0.96	V
I_{FAV}	*average forward current*	T_C = 85°C	T_{VJ} = 150°C			80	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			0.30	V
r_F	*slope resistance* }					4	mΩ
R_{thJC}	*thermal resistance junction to case*					0.8	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.1		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			150	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			800	A
C_J	*junction capacitance*	V_R = 5 V f = 1 MHz	T_{VJ} = 25°C		2.93		nF

Package SOT-227B (minibloc)					Ratings			
Symbol	**Definition**	**Conditions**			**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal					100	A
T_{VJ}	*virtual junction temperature*				-40		150	°C
T_{op}	*operation temperature*				-40		125	°C
T_{stg}	*storage temperature*				-40		150	°C
Weight						30		g
M_D	*mounting torque*				1.1		1.5	Nm
M_T	*terminal torque*				1.1		1.5	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*		*terminal to terminal*	10.5	3.2			mm
$d_{Spb/Apb}$			*terminal to backside*	8.6	6.8			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA		3000			V
		t = 1 minute			2500			V

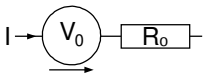
Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSS2x81-0045B	DSS2x81-0045B	Tube	10	470422

Equivalent Circuits for Simulation

** on die level* T_{VJ} = 150°C



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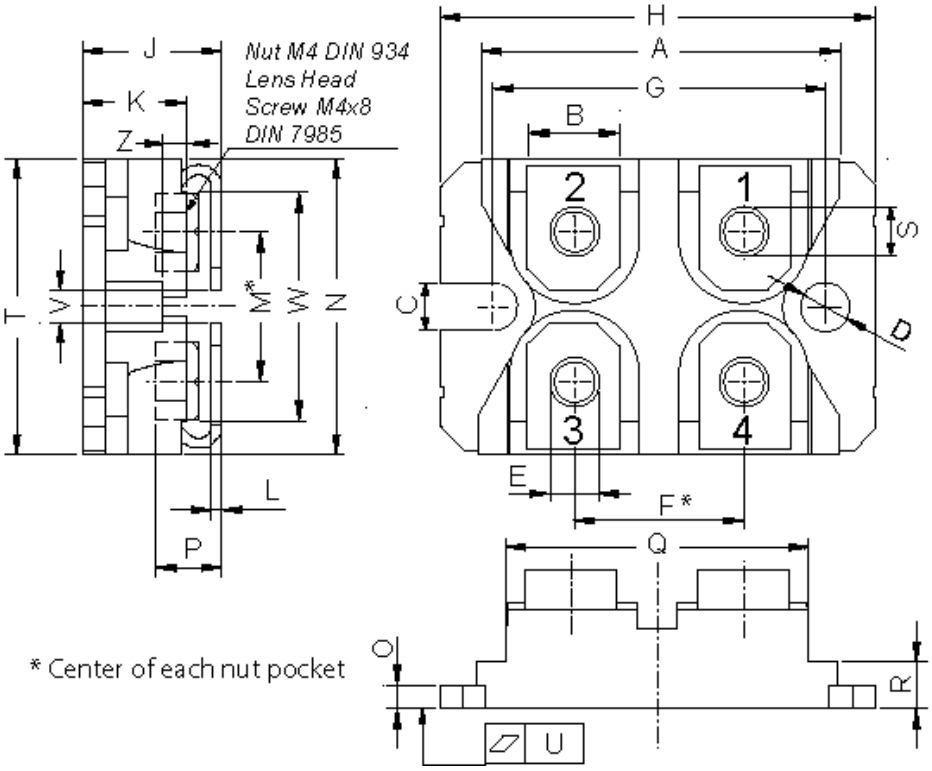
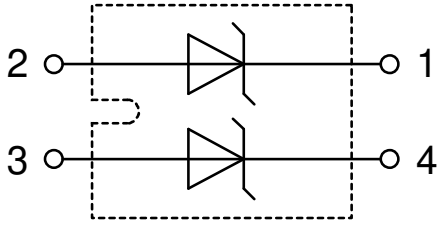
$V_{0\,max}$	*threshold voltage*	0.3	V
$R_{0\,max}$	*slope resistance **	2.2	mΩ

Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106



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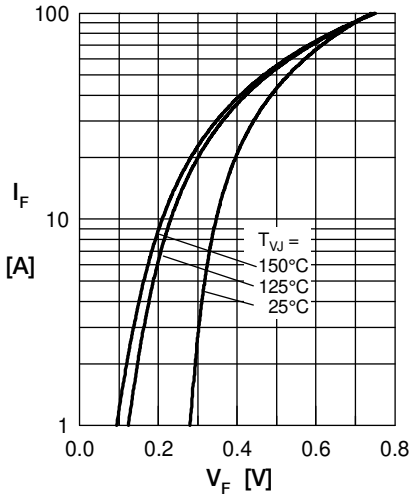

Fig. 1 Max. forward voltage drop characteristics

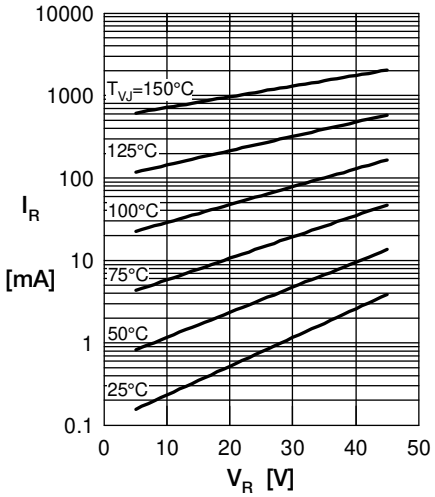

Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

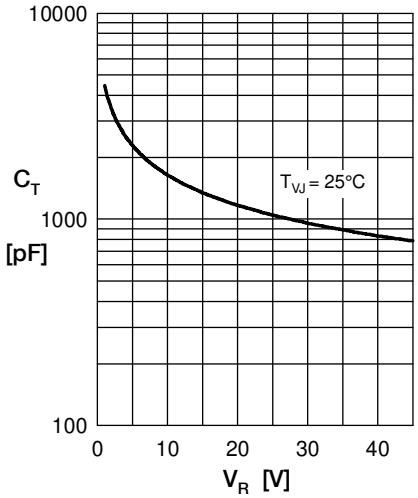

Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

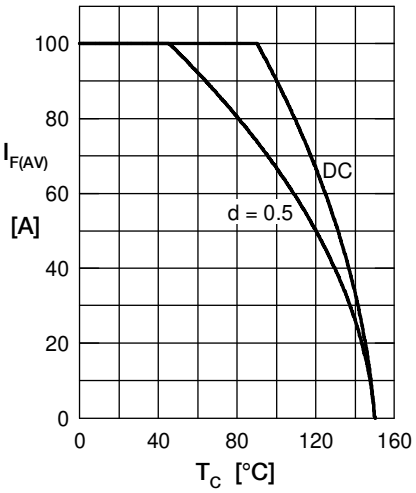

Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

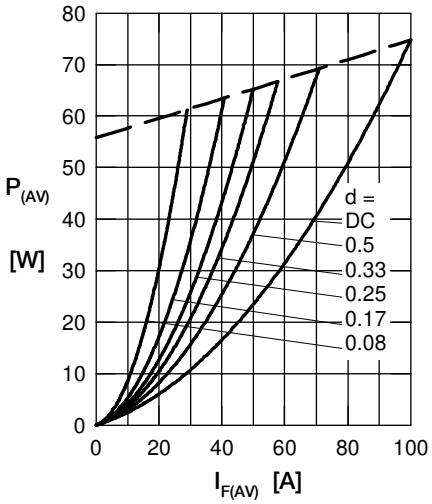

Fig. 5 Forward power loss characteristics

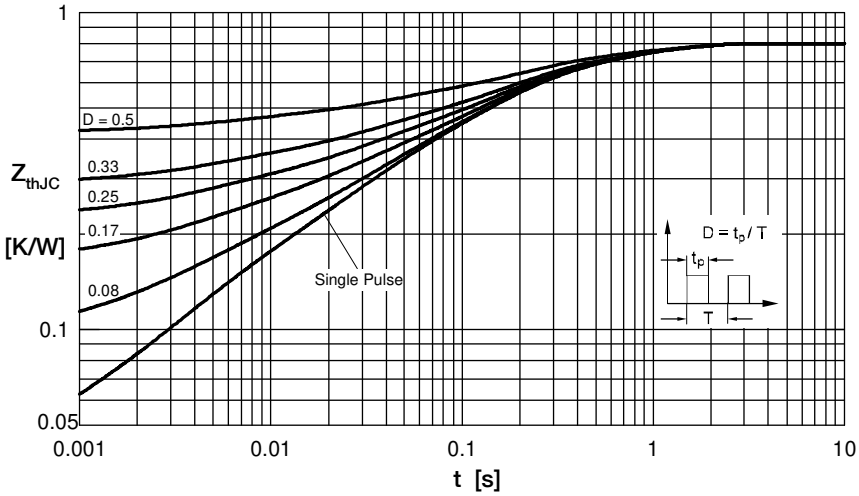

Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode